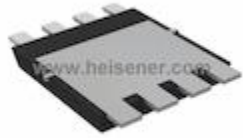


TPW1R306PL,L1Q Information


For Reference Only

Part Number [TPW1R306PL,L1Q](#)
Manufacturer Toshiba Semiconductor and Storage
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - Single](#)
Description X35 PB-F POWER MOSFET TRANSISTOR
Package 8-PowerWDFN
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


[Request a Quote](#)
Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


TPW1R306PL,L1Q Specifications

Manufacturer Part Number	TPW1R306PL,L1Q
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Package	8-PowerWDFN
Series	U-MOSIX-H
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	60V
Current - Continuous Drain (Id) @ 25°C	260A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	-
Gate Charge (Qg) (Max) @ Vgs	-
Input Capacitance (Ciss) (Max) @ Vds	-
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	960mW (Ta), 170W (Tc)
Rds On (Max) @ Id, Vgs	-
Operating Temperature	-
Mounting Type	Surface Mount
Supplier Device Package	8-DSOP Advance
Package / Case	8-PowerWDFN

[Report errors?](#)

TPW1R306PL,L1Q Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

TPW1R306PL,L1Q Payment Methods



TPW1R306PL,L1Q Shipping Methods



If you have any question about TPW1R306PL,L1Q, please do not hesitate to contact us!

Website: <https://www.heisener.com>

E-mail: salesdept@heisener.com